

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
650V	330mΩ@10V	11A

Feature

- Optimized body diode reverse recovery performance
- Low on-resistance and low conduction losses
- Ultra Low Gate Charge cause lower driving requirements
- ESD protected
- Suffix "-Q1" for AEC-Q101

Application

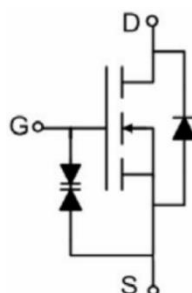
- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible power supply (UPS)
- LLC Half-bridge

Package

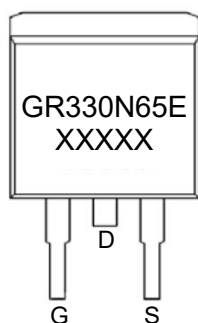


TO-263AB

Circuit Diagram



Marking



Absolute Maximum Ratings (T_C=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	650	V
Gate-Source Voltage AC(f > 1Hz)	V _{GS}	±30	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current	I _D	11	A
Continuous Drain Current(T _C =100°C)	I _D (100°C)	7.7	A
Pulsed Drain Current ¹⁾	I _{DM}	44	A
Power Dissipation	P _D	107	W
Thermal Resistance,Junction-to-Case	R _{θJC}	1.4	°C/W
Thermal Resistance from Junction to Ambient	R _{θJA}	62	°C/W
Avalanche Current ²⁾	I _{AS}	3	A
Junction Temperature	T _J	175	°C
Storage Temperature	T _{STG}	-55 ~ +175	°C

Electrical Characteristics (T_A=25 °C unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	650			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =650V,V _{GS} = 0V,T _C =25°C			1	μA
		V _{DS} =650V,V _{GS} = 0V,T _C =125°C			100	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} = 0V			±10	μA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	3.0	3.5	4.0	V
Drain-Source on-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =5.5A		300	330	mΩ
Dynamic Characteristics ³⁾						
Input Capacitance	C _{iss}	V _{DS} =50V,V _{GS} =0V,f =1MHz		847		pF
Output Capacitance	C _{oss}			31		
Reverse Transfer Capacitance	C _{rss}			4		
Gate Resistance	R _g	f =1MHz, open drain		18		Ω
Total Gate Charge	Q _g	V _{DS} =480V,V _{GS} =10V, I _D =5.5A		17		nC
Gate-Source Charge	Q _{gs}			4.4		
Gate-Drain Charge	Q _{gd}			4.9		
Gate Plateau Volitage	V _{gp}			5.4		
Turn-on Delay Time	t _{d(on)}	V _{DD} =480V, V _{GS} =10V, I _D =5.5A, R _G =1.7Ω		10		nS
Turn-on Rise Time	t _r			7		
Turn-off Delay Time	t _{d(off)}			55		
Turn-off Fall Time	t _f			8		
Source-Drain Diode Characteristics						
Diode Forward Current	I _{SD}	T _C =25°C			11	A
Diode Forward Pulse Current	I _{SDM}				44	A
Diode Forward voltage	V _{SD}	T _J =25°C,V _{GS} =0V, I _{SD} =11A			1.2	V
Reverse Recovery Time	t _{rr}	T _J =25°C,I _F =5.5A, di/dt=100A/μs		200		nS
Reverse Recovery Charge	Q _{rr}			1.6		uC
Peak Reverse Recovery Current	I _{rrm}			16		A

Notes:

- 1) Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2) T_J=25 °C, V_{DD}=50V, V_G=10V, R_g=25Ω.
- 3) Guaranteed by design, not subject to production.

Typical Characteristics

Figure1. Safe operating area

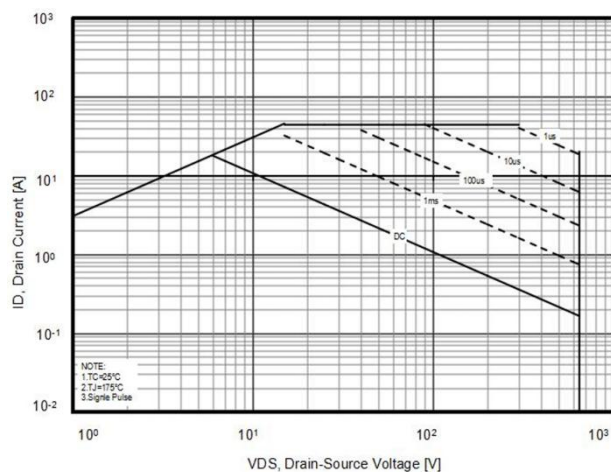


Figure2. Capacitance

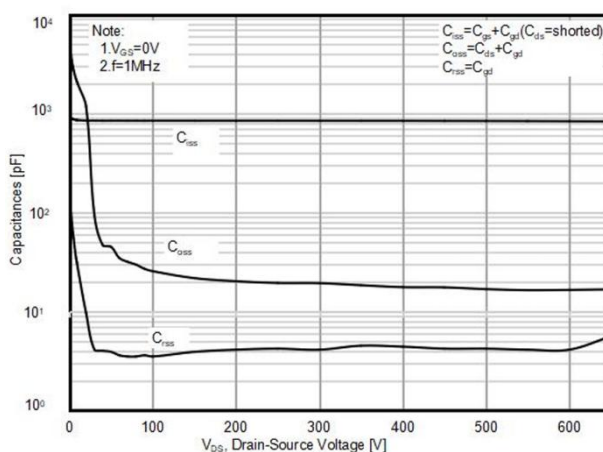


Figure3. Transfer characteristics

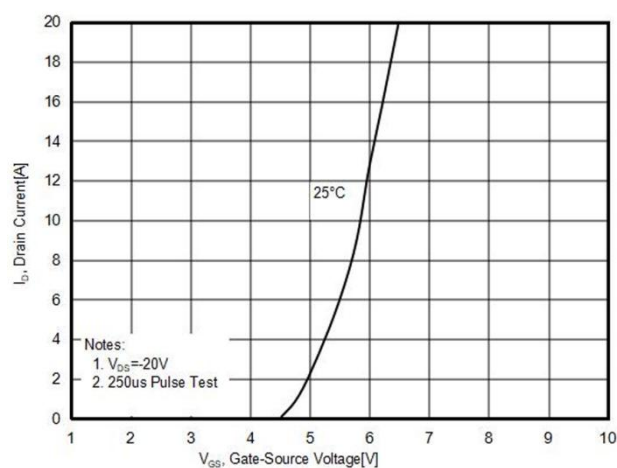


Figure4. Output characteristics

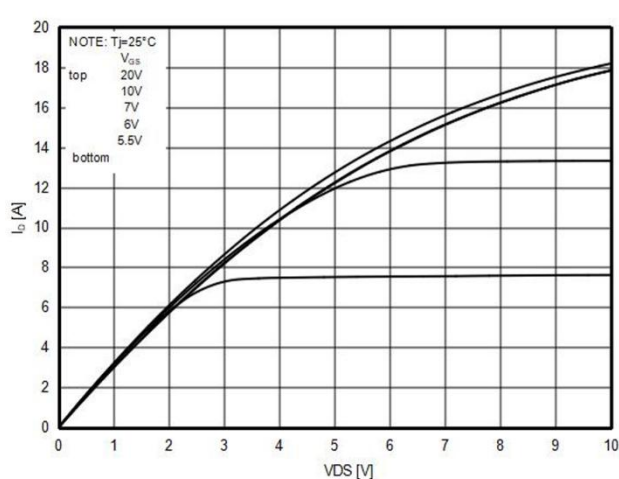


Figure5. $R_{DS(ON)}$ vs Junction Temperature

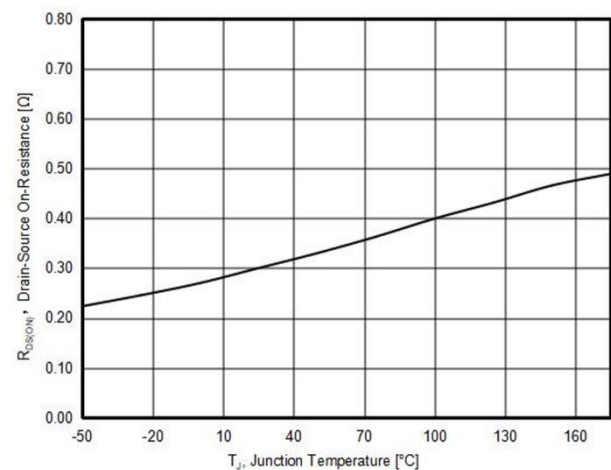
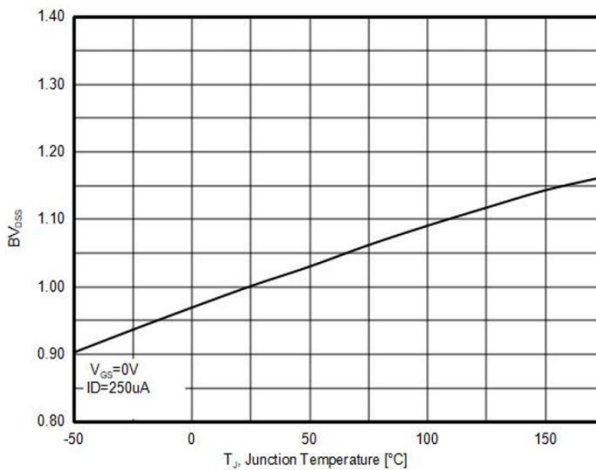


Figure6. BV_{DSS} vs Junction Temperature



Typical Characteristics

Figure7. Maximum I_D vs Junction Temperature

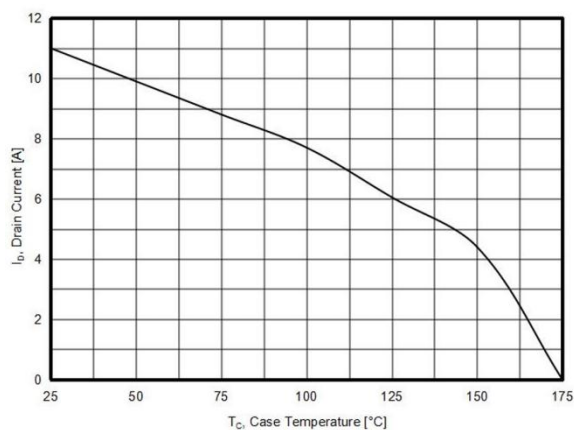


Figure8. Gate charge waveforms

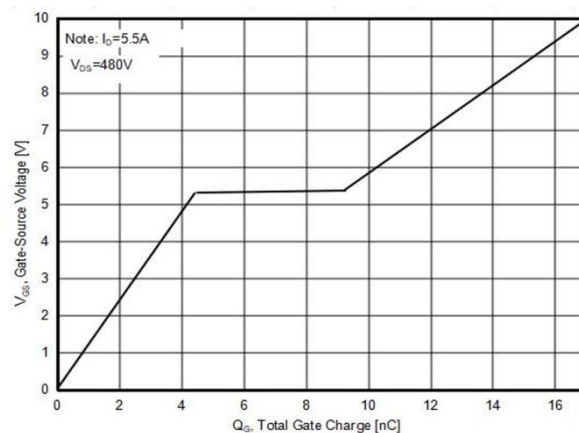


Figure9. Static drain-source on resistance

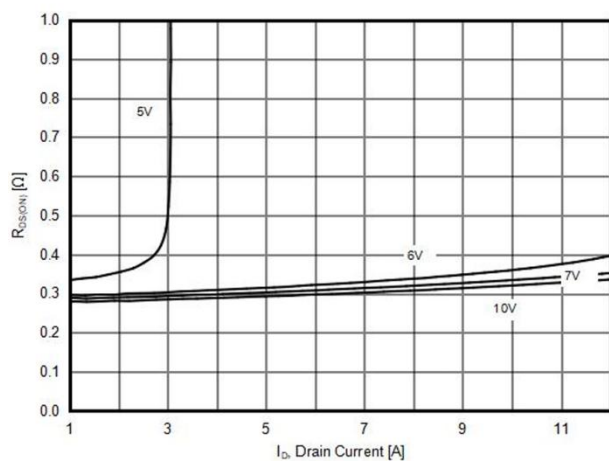
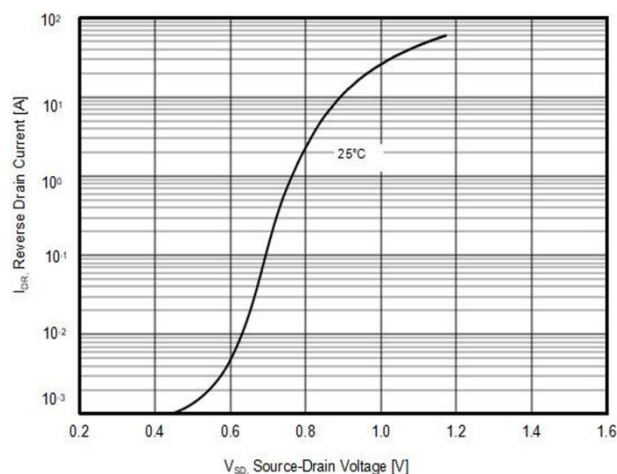
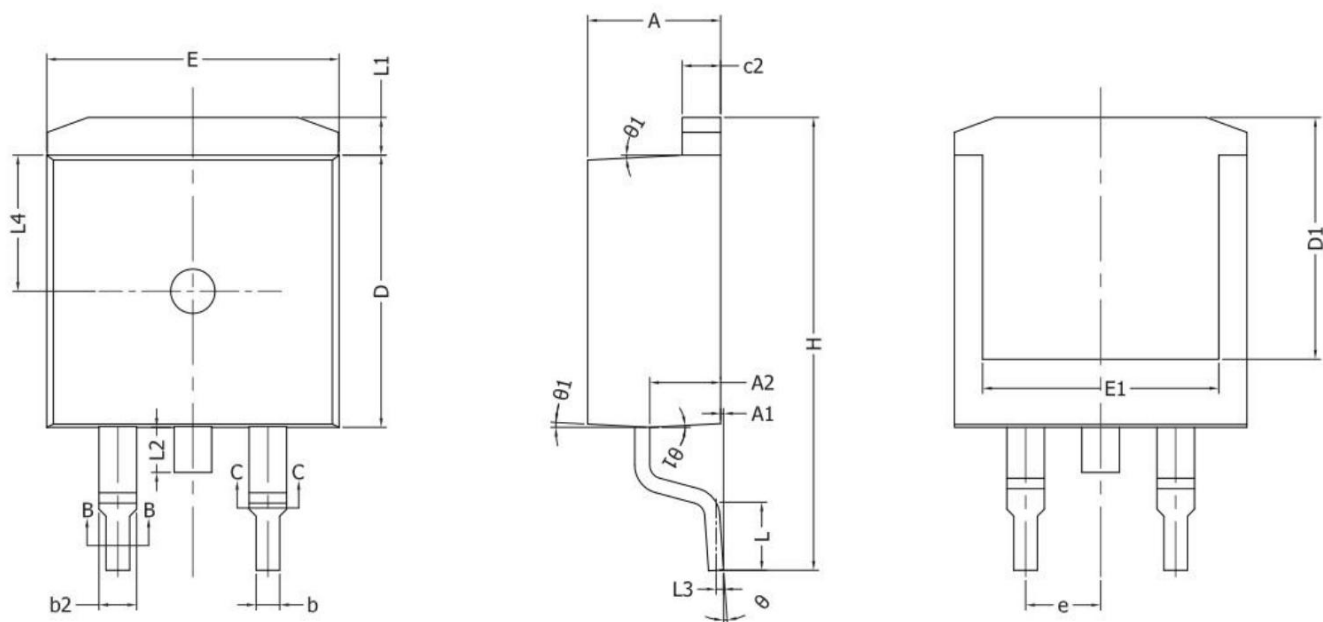


Figure10. Source-Drain Diode Forward Voltage



TO-263AB Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.400	4.600	0.173	0.181
A1	0.000	0.250	0.000	0.010
A2	2.200	2.600	0.087	0.102
b	0.760	0.890	0.030	0.035
b1	0.750	0.850	0.030	0.033
b2	1.230	1.370	0.048	0.054
b3	1.220	1.320	0.048	0.052
c	0.470	0.600	0.019	0.024
c1	0.460	0.560	0.018	0.022
c2	1.250	1.350	0.049	0.053
D	9.100	9.300	0.358	0.366
D1	8.000	-	0.315	-
E	9.800	10.000	0.386	0.394
E1	7.800	-	0.307	-
e	2.540BSC		0.100BSC	
H	14.900	15.700	0.587	0.618
L	2.000	2.600	0.079	0.102
L1	1.170	1.400	0.046	0.055
L2		1.750		0.069
L3	0.250REF		0.010REF	
L4	4.600REF		0.181REF	